













- ► EMC SMD Top View
- ➤ 3838 2.98t Series
- ► Infrared (IR) 850nm

NOF60S70BF









#### **FEATURES:**

- Package: Black Ceramic Single Junction SMT Package
- Forward Current: 1A
- Pulse Forward Current (max.): 3A
- Forward Voltage (typ.): 1.7V

3838 2.98t Series

- Radiant Power (typ.): 950mW@1A
- Radiant Intensity (typ.): 780mW/sr@1A
- Colour: Infrared (IR)
- Peak Wavelength (typ.): 850nm
- Viewing Angle: 40°
- Operating Temperature: -40~+105°C
- Storage Temperature: -40~+105°C
- **Grouping Parameters:** 
  - Forward Voltage
  - **Radiant Power**
  - Peak Wavelength Soldering Methods: Reflow
- MSL Level: MSL2 according to J-STD020
- **Corrosion Robustness Class: 3B**
- Packing: 12mm tape with max.600/reel, Ø178mm (7")

#### **APPLICATIONS:**

- Automotive
- Security Camera
- **Motion Detection**
- Night Viewer
- Surveillance
- **Data Communication**



### **CHARACTERISTICS:**

# Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	lf	1000	mA
Power Consumption	P <sub>tot</sub>	2	W
Pulse Forward Current	IPF	3	А
Reverse Voltage	V <sub>R</sub>	5	V
Reverse Current @5V	I <sub>R</sub>	10	μΑ
Junction Temperature	Tj	125	°C
Thermal Resistance Junction to Solder Point	R <sub>th</sub>	typ. 4.5; typ. 9	K/W
Electrostatic Discharge (HBM: MIL-STD-883 C 2)	ESD	2	kV
Operating Temperature	T <sub>OPR</sub>	-40~+105	°C
Storage Temperature	T <sub>STG</sub>	-40~+105	°C
Soldering Temperature	T <sub>SOL</sub>	260	°C

## Electrical & Optical Characteristics (Ta=25°C, I<sub>F</sub>=1A, t<sub>p</sub>=10ms)

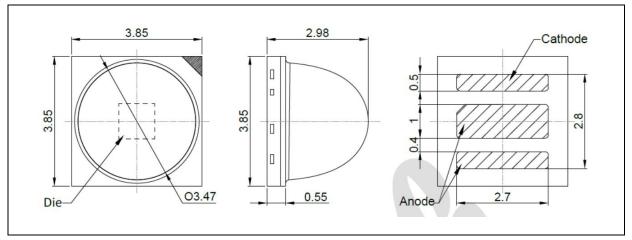
Parameter	Parameter Symbol Values				Unit	Test
Parameter	Зуппоп	Min.	Тур.	Max.	Offic	Condition
Forward Voltage	$V_{F}$	1.5	1.7	2.0	V	I <sub>F</sub> =1Α t <sub>p</sub> =100μs
Radiant Power	Фе	800	950	1100	mW	I <sub>F</sub> =1Α t <sub>p</sub> =100μs
Radiant Intensity	l <sub>e</sub>	690	780	950	mW/sr	I <sub>F</sub> =1Α t <sub>p</sub> =100μs
Peak Wavelength	$\Lambda_{P}$		850		nm	I <sub>F</sub> =1A
Spectral Bandwidth	Δλ		40		nm	I <sub>F</sub> =1A
Viewing Angle	2θ <sub>1/2</sub>		40		deg	I <sub>F</sub> =1A

<sup>1.</sup> Radiant Power (Po)  $\pm 10\%$ , Forward Voltage (VF)  $\pm 0.1V$ , Viewing angle( $2\theta_{1/2}$ )  $\pm 10^\circ$ 



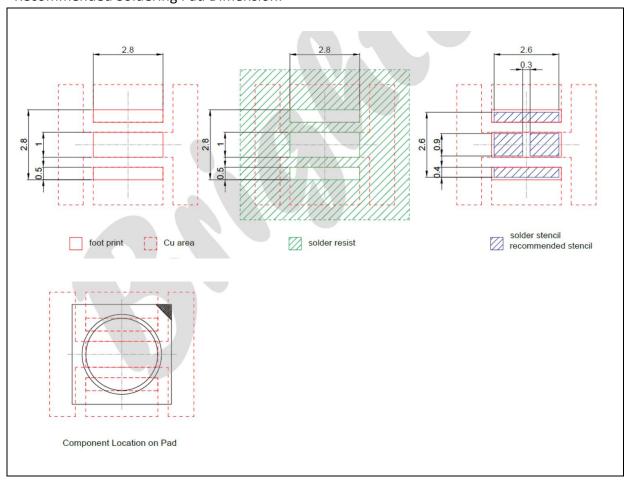
### **OUTLINE DIMENSION:**

### Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.05mm, unless otherwise noted.

## **Recommended Soldering Pad Dimension:**



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



## **BINNING GROUPS:**

# Forward Voltage Classifications (I<sub>F</sub>=1A; t<sub>p</sub>=10ms):

Code	Min.	Max.	Unit
DF	1.5	2.0	V

## Radiant Power Classifications (I<sub>F</sub>=1A; t<sub>p</sub>=10ms):

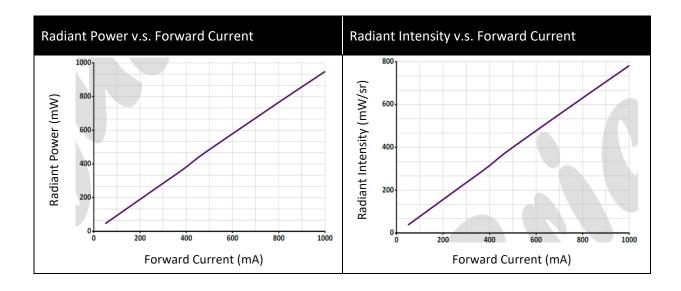
Code	Min.	Max.	Unit
PA8	800	900	
PA9	900	1000	mW
PB0	1000	1100	

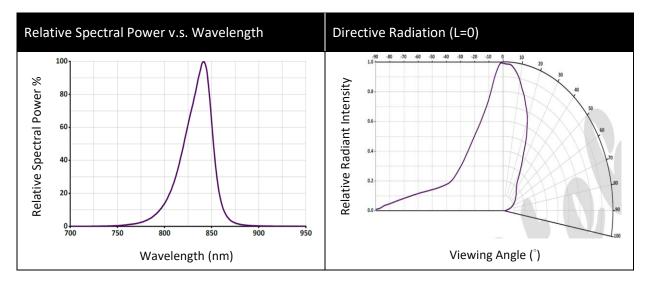
# Peak Wavelength Classifications (I<sub>F</sub>=1A; t<sub>p</sub>=10ms):

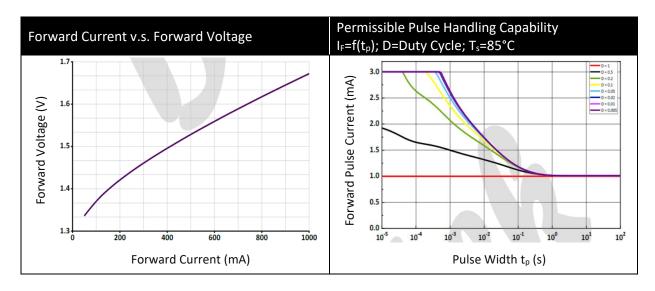
Code	Min.	Max.	Unit
F3	840	870	nm



#### **ELECTRO-OPTICAL CHARACTERISTICS:**

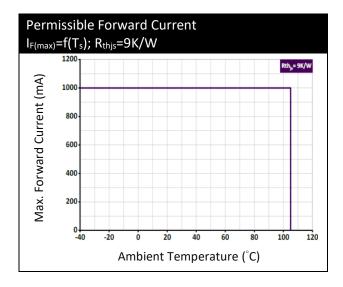








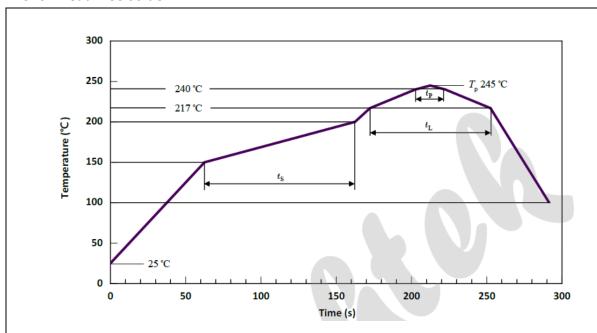
## **ELECTRO-OPTICAL CHARACTERISTICS:**





#### **RECOMMENDED SOLDERING PROFILE:**

#### Reflow Lead-free Solder:



Profile Feature	Symbol	Pb-	Free (SnAgCu) Assembly		Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat 25 °C to 150 °C		A	2	3	K/s
Time ts T <sub>Smin</sub> to T <sub>Smax</sub>	ts	60	100	120	s
Ramp-up rate to peak T <sub>Smax</sub> to T <sub>P</sub>			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	tL		80	100	s
Peak temperature	ТР		245	260	°C
Time within 5 °C of the specified peak temperature TP - 5 K	T <sub>P</sub>	10	20	30	s
Ramp-down Rate T <sub>P</sub> to 100 °C			3	4	K/s
Time				490	
25 °C to T <sub>P</sub>				480	S

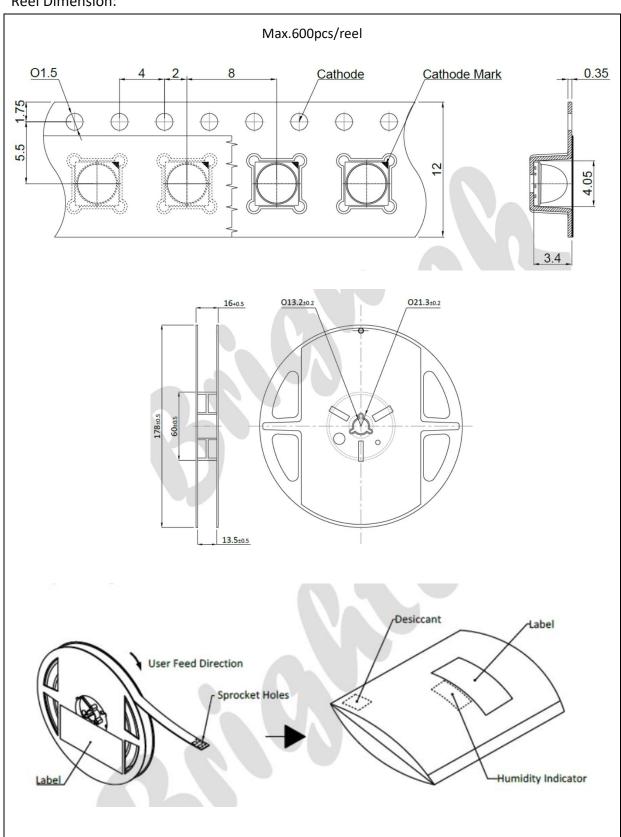
#### Note:

- 1. Maximum reflow soldering: 2 times.
- 2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



## **PACKING SPECIFICATION:**

#### Reel Dimension:





#### **PRECAUTIONS OF USE:**

#### Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

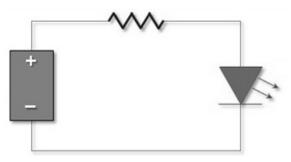
#### Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

#### **Testing Circuit:**



Must apply resistor(s) for protection (over current proof).

#### Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

### ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.



# **REVISION RECORD:**

Version	Date	Summary of Revision
A1.0	22/05/2022	Datasheet set-up.
A1.1	04/09/2024	Add packing and bin information.